High Voltage Transistor

PNP Silicon

The MMBT5401M3 device is a spin-off of our popular SOT-23 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-723 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	-150	Vdc
Collector – Base Voltage	V _{CBO}	-160	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ι _C	-60	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$ Derate Above 25°C	PD	130 1.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	470	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

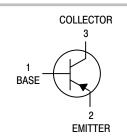
1. FR-5 @ 100 mm², 1.0 oz. copper traces, still air.



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MARKING DIAGRAM



RJ = Specific Device Code M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT5401M3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSVMMBT5401M3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Noise Figure

(I_C = -200 μ A, V_{CE} = -5.0 V, R_S = 10 Ω , f = 1.0 kHz)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = -1.0 \text{ mA}, I_B = 0)$	V _{(BR)CEO}	-150	_	-	V
Collector – Base Breakdown Voltage $(I_C = -100 \ \mu A, I_E = 0)$	V _{(BR)CBO}	-160	_	-	V
Emitter – Base Breakdown Voltage ($I_E = -10 \ \mu A, I_C = 0$)	V _{(BR)EBO}	-5.0	_	-	V
Collector–Base Cutoff Current $(V_{CB} = -120 \text{ V}, I_E = 0)$	I _{CBO}	-	-1.6	-100	nA
Emitter Cutoff Current ($V_{BE} = -5 V$)	I _{EBO}	-	-0.20	-100	nA
ON CHARACTERISTICS					
DC Current Gain ($I_C = -1.0 \text{ mA}, V_{CE} = -5.0 \text{ V}$) ($I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V}$) ($I_C = -50 \text{ mA}, V_{CE} = -5.0 \text{ V}$)	h _{FE}	50 60 20	80 90 40	_ 240 _	_
Collector – Emitter Saturation Voltage ($I_C = -10$ mA, $I_B = -1.0$ mA) ($I_C = -50$ mA, $I_B = -5.0$ mA)	V _{CE(sat)}	-	-0.09 -0.15	-0.25 -0.60	V
Base – Emitter Saturation Voltage ($I_C = -10 \text{ mA}, I_B = -1.0 \text{ mA}$) ($I_C = -50 \text{ mA}, I_B = -5.0 \text{ mA}$)	V _{BE(sat)}		-0.76 -0.92	-1.0 -1.0	V
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain — Bandwidth Product ($I_C = -10$ mA, $V_{CE} = -5.0$ V, f = 100 MHz)	f _T	100	180	300	MHz
Input Capacitance $(V_{EB} = -3 \text{ V}, I_C = 0, f = 1.0 \text{ MHz})$	C _{ibo}	_	12.5	15	pF
Output Capacitance $(V_{CB} = -10 \text{ V}, I_E = 0, f = 1.0 \text{ MHz})$	C _{obo}	-	1.5	6.0	pF
Small Signal Current Gain (I _C = -1.0 mA, V _{CE} = -10 V, f = 1.0 kHz)	h _{fe}	40	_	200	_

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

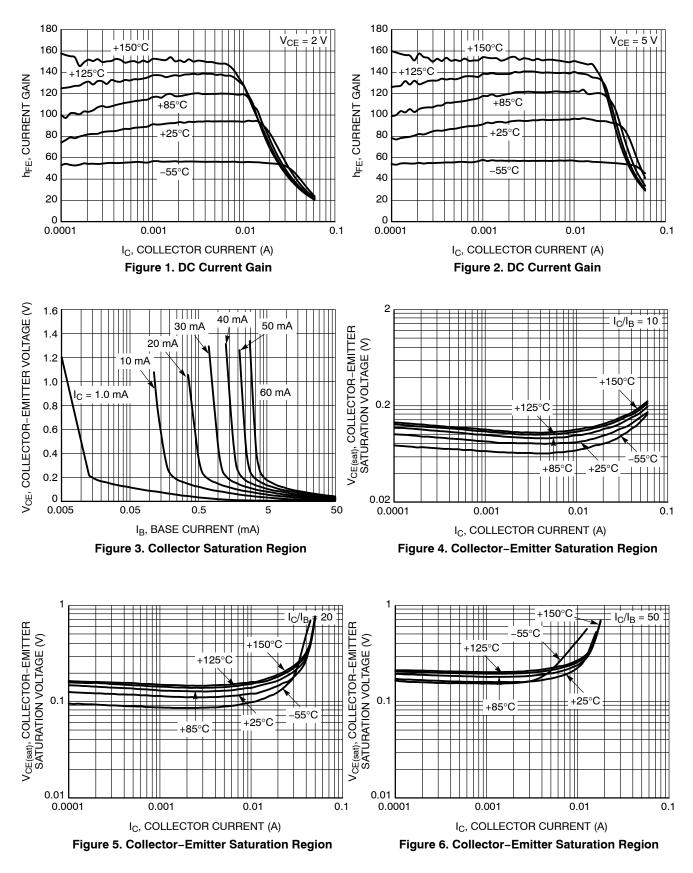
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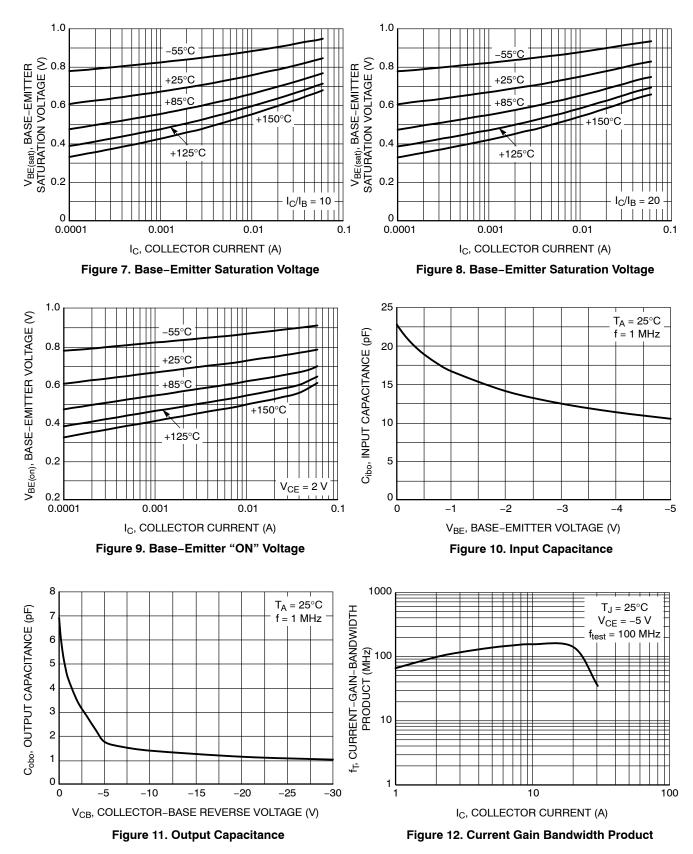
dB

8.0

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TYPICAL CHARACTERISTICS





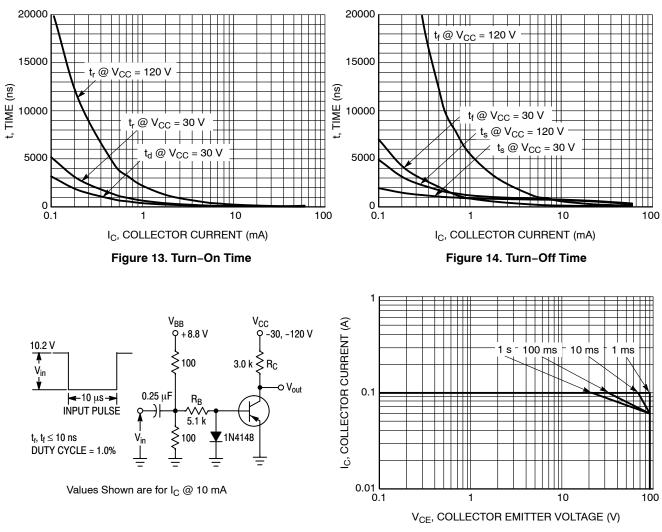
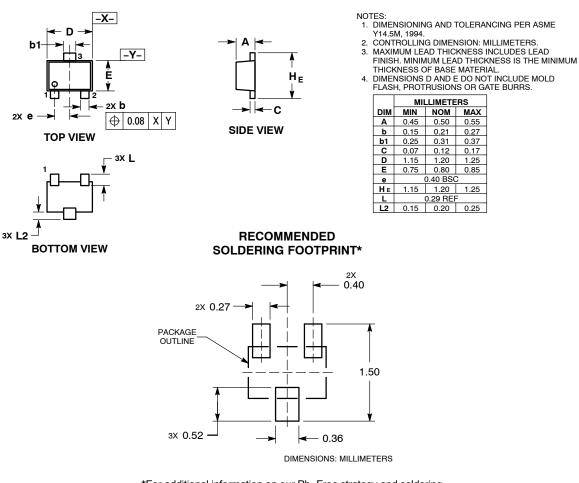


Figure 15. Switching Time Test Circuit

Figure 16. Safe Operating Area

PACKAGE DIMENSIONS

SOT-723 CASE 631AA ISSUE D



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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